

Coaxial Laser Diode Module

1. Features:

- Coaxial pigtail package;
- Built-in InGaAs/PIN monitor;
- Integrated optical isolator;
- Operating temperature range: -20 to 80°C.

2. Applications

- CDMA/GSM transmission system;
- WDM system;
- CATV Return-path;
- Other analog transmission system.

3. Absolute Maximum Ratings:

| Parameter | Symbol | Condition | Min. | Max. | Unit |
|--------------------------------------|-----------|---------------------|------|--------|------|
| LD Reverse voltage | V_{RLD} | CW | - | 2 | V |
| LD Forward current | I_{FLD} | CW | - | 120 | mA |
| PD Reverse voltage | V_{RPD} | CW | - | 15 | V |
| PD Forward current | I_{FPD} | CW | - | 2 | mA |
| Lead soldering temperture/Time | T_s | - | | 260/10 | °C/S |
| Fiber yield strength | - | - | | 1 | kgf |
| Fiber bend radius | - | - | 30 | | mm |
| Operating temperature ⁽¹⁾ | T_{OP} | Case temperature | -20 | +80 | °C |
| Storage temperature | T_{STG} | Ambient temperature | -40 | +85 | °C |

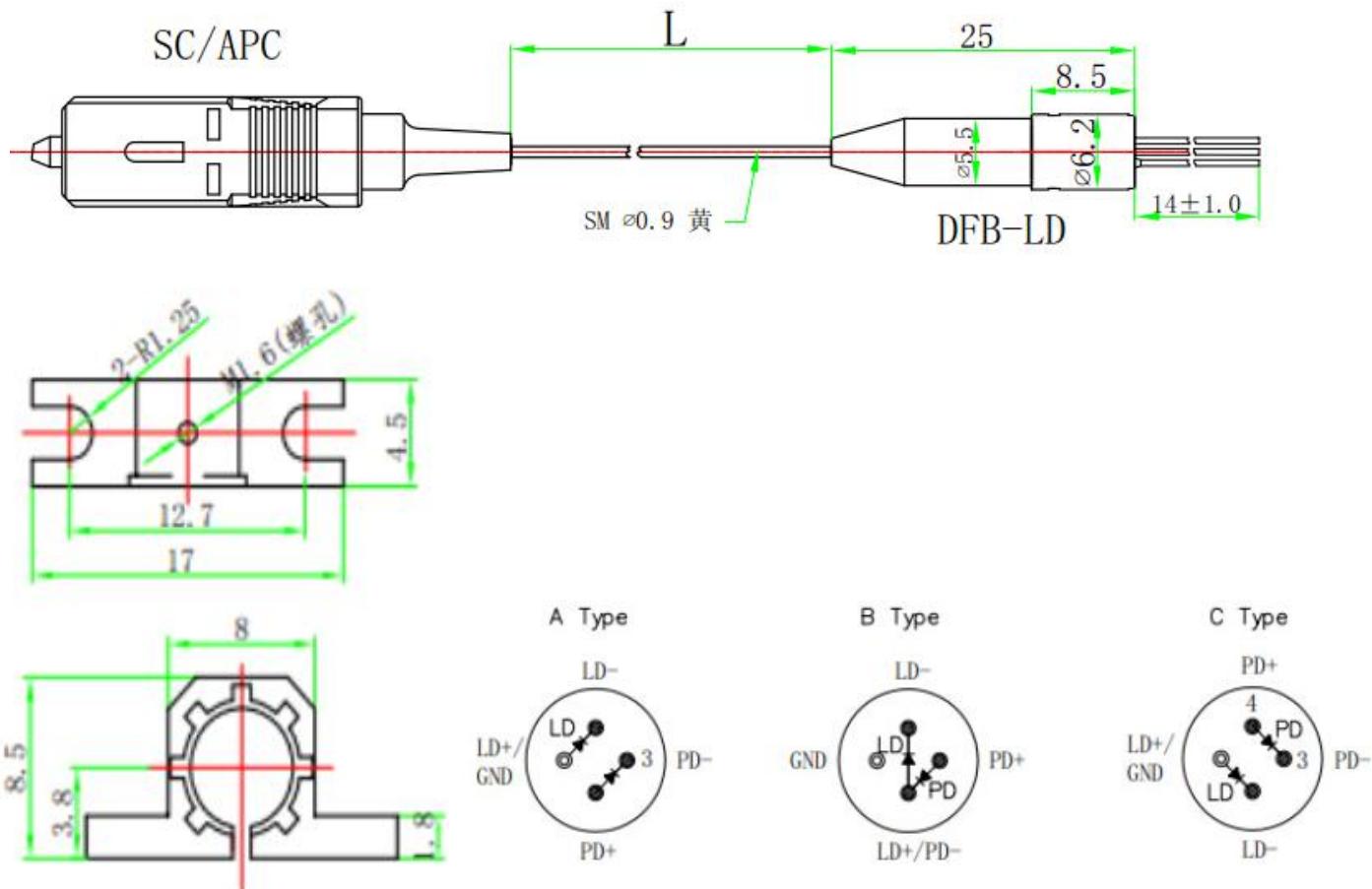
Note: (1) Operating Temperature is available in 0~70°C or -20~80°C.

4. Optical-Electro Characteristics:

| Parameter | Symbol | Condition | | Min. | Typ. | Max. | Unit |
|----------------------|-------------|------------------------------------|-----|------------------|-------------|------------------|------|
| Center wavelength | λ_C | $P_O = P_F$ | FP | 1310, 1550 | | | nm |
| | | | DFB | 1270 | - | 1610 | |
| Optical output power | P_F | $I_F = I_{TH} + 20\text{mA}$ | | 2 | - | - | mW |
| Center wavelength | λ_C | $P_O = P_F$ | FP | $\lambda_C - 20$ | λ_C | $\lambda_C + 10$ | nm |
| | | | DFB | $\lambda_C - 10$ | | $\lambda_C + 10$ | |
| Threshold current | I_{TH} | FP | | 5 | - | 15 | mA |
| | | DFB | | 4 | | 10 | |
| Operating voltage | V_F | - | | - | 1.2 | 1.5 | pF |
| Rise time/Fall time | T_R/T_F | $I_F = I_{TH}, P_O = P_F(20-80)\%$ | | - | - | 0.4 | ns |
| Monitor current | I_M | $P_O = P_F$ | | 0.1 | - | 1 | mA |
| Capacitance | C | - | | - | 10 | 15 | PF |

| Spectral width(-20dB) | $\Delta\lambda$ | FP | $I_F = I_{TH} + 20$ mA | - | 0.1 | 1.0 | nm |
|----------------------------------------|-----------------|--------------------|------------------------|------|-----|------|-------|
| | | DFB | mA | | 1.6 | 2.5 | |
| Tracking error | TE | - | - | -1.0 | - | 1.0 | dB |
| Optical isolation | I _{SO} | - | - | 30 | - | - | dB |
| 2Sec order inter-modulation distortion | IMD2 | - | - | - | - | -50 | dBc |
| 3rd order inter-modulation distortion | IMD3 | - | - | - | - | -60 | dBc |
| Relative intensity noise | RIN | - | - | - | - | -145 | dB/Hz |
| Side mode suppression ration | SMSR | $P_o = 2\text{mW}$ | 40 | - | - | - | dB |

5. Package Drawing&PIN-OUT Definition(Unit:mm):



6. Order Information:

| BLD | -X | XX | XX | X | -X | -XX |
|-------------|----------------------------|----------------------------------|-----------------------------|-------------------------------------|-----------------------|-----------------------------------|
| LD | Chip type | Wavelength | Output power | PIN-OUT | Isolator | Connector |
| Laser diode | F: FP D: DFB C: CWDM | 31: 1310nm 55: 1550nm CWDM | 02: 2mW 04: 4mW Other | A: Type A B: Type B C: Type C | I: With N: Without | FA: FC/APC SA: SC/APC Other |